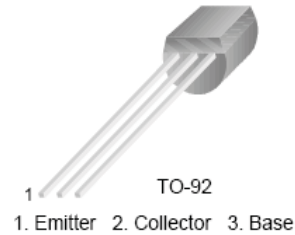


# 2N6076

## PNP Small Signal Transistor

### Features

- $V_{CE0}$  .....25V(Min)
- $h_{FE}$  ..... 100(Min) @  $V_{CE}=10V, I_C=10mA$
- Pb free



### Absolute Maximum Ratings $T_a=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	-25	V
$V_{CEO}$	Collector-Emitter Voltage	-25	V
$V_{EBO}$	Emitter-Base Voltage	-5	V
$I_C$	Collector Current	500	mA
$T_J$	Junction Temperature	150	$^{\circ}C$
$T_{STG}$	Storage Temperature Range	-55 ~ 150	$^{\circ}C$

\* 1. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### Thermal Characteristics\* $T_a=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Max	Unit
$P_C$	Collector Power Dissipation, by $R_{\theta JA}$	625	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	$^{\circ}C/W$

- \* 2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.  
 3. These ratings are based on a maximum junction temperature of 150 degrees C.  
 4. Minimum land pad.

### Electrical Characteristics\* $T_a=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Unit
$BV_{CBO}$	Collector-Base Breakdown Voltage	$I_C = -100\mu A, I_E = 0$	-25		V
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C = -10mA, I_B = 0$	-25		V
$BV_{EBO}$	Emitter-Base Breakdown Voltage	$I_E = -10\mu A, I_C = 0$	-5		V
$I_{CBO}$	Collector Cut-off Current	$V_{CE} = -25V$ $V_{CE} = -25V, T = +100^{\circ}C$		-100 10	nA uA
$I_{CES}$	Collector Cut-off Current	$V_{CE} = -25V$		-100	nA
$I_{EBO}$	Emitter Cut-off Current	$V_{CE} = -3V$		-100	nA
$h_{FE}$	DC Current Gain	$V_{CE} = 1V, I_C = -10mA$	100	500	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -10mA, I_B = -1mA$		-0.25	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = -10mA, I_B = -1mA$		-0.80	V
$V_{BE(on)}$	Base-Emitter On Voltage	$V_{CE} = -10V, I_C = -10mA$	-0.5	-1.2	V
$C_{cb}$	Output Capacitance	$V_{CB} = -10V, f = 1MHz$	1	13	pF
$h_{fe}$	Small Signal Current Gain	$V_{CE} = -10V, I_C = 10mA, f = 1kHz$	100	750	

\* DC Item are tested by Pulse Test : Pulse Width $\leq$ 300us, Duty Cycle $\leq$ 2%



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